

■ PRODUCT CHARACTERISTICS

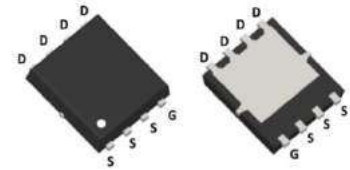
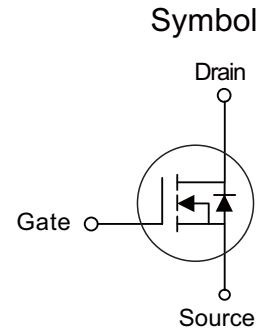
VDSS	30V
R _{DS(on)} Typ(@V _{GS} =10 V)	3.2mΩ
R _{DS(on)} Typ(@V _{GS} =4.5 V)	5mΩ
ID	120A

■ APPLICATIONS

- * Power switching application
- * Hard switched and high frequency circuits
- * Uninterruptible power supply

■ FEATURES

- * High density cell design gor ultra low Rdson
- * Excellent package for good heat DISSIPATION



■ ORDER INFORMATION

Order codes		Package	Packing
Halogen-Free	Halogen		
N/A	MOT3136J	PDFN3x3-8L	5000 pieces /Reel

■ ABSOLUTE MAXIMUM RATINGS (T_C = 25°C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	120	A
Drain Current-Continuous(T _C =100°C)	I _D (100°C)	84	A
Pulsed Drain Current	I _{DM}	420	A
Maximum Power Dissipation	P _D	120	W
Single pulse avalanche energy	E _{AS}	350	mJ
Thermal Resistance,Junction-to-Case	R _{θJC}	1.25	°C/W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 To 175	°C

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
On characteristics						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1	1.5	3	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	3.2	4	mΩ
		V _{GS} =4.5V, I _D =20A	-	5	6	mΩ
Gate resistance	R _G	F=1.0MHz	-	1.2	-	Ω
Forward Transconductance	g _{FS}	V _{DS} =5V, I _D =5A	10	-	-	S
Dynamic characteristics						
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, F=1.0MHz	-	2800	-	PF
Output Capacitance	C _{oss}		-	260	-	PF
Reverse Transfer Capacitance	C _{rss}		-	240	-	PF
Switching characteristics						
Turn-on Delay Time	t _{d(on)}	V _{GS} =10V, V _{DS} =20V R _L =0.75Ω, R _{GEN} =3Ω	-	11	-	nS
Turn-on Rise Time	t _r		-	10	-	nS
Turn-Off Delay Time	t _{d(off)}		-	38	-	nS
Turn-Off Fall Time	t _f		-	11	-	nS
Total Gate Charge	Q _g	V _{GS} =10V, V _{DS} =15V, I _D =20A	-	79	-	nC
Gate-Source Charge	Q _{gs}		-	9	-	nC
Gate-Drain Charge	Q _{gd}		-	18	-	nC
Drain-source diode characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A	-	-	1.2	V
Diode Forward Current	I _S		-	-	120	A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =20A di/dt = 100A/μs	-	58	-	nS
Reverse Recovery Charge	Q _{rr}		-	115	-	nC

■ TYPICAL CHARACTERISTICS

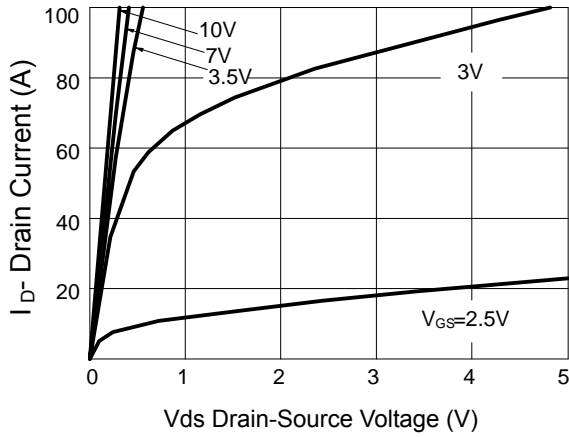


Figure 1: Output characteristics

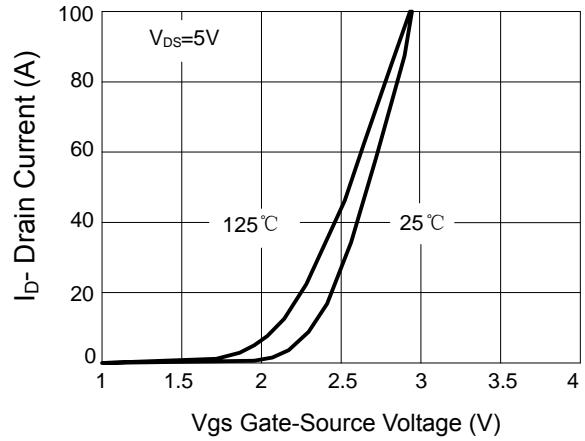


Figure 2: Transfer characteristics

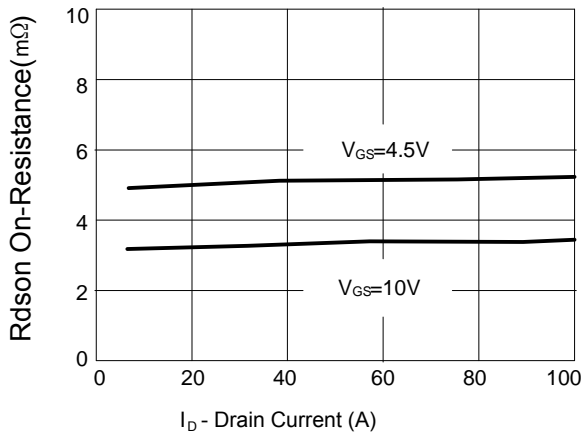


Figure 3: $R_{DS(on)}$ -drain-current

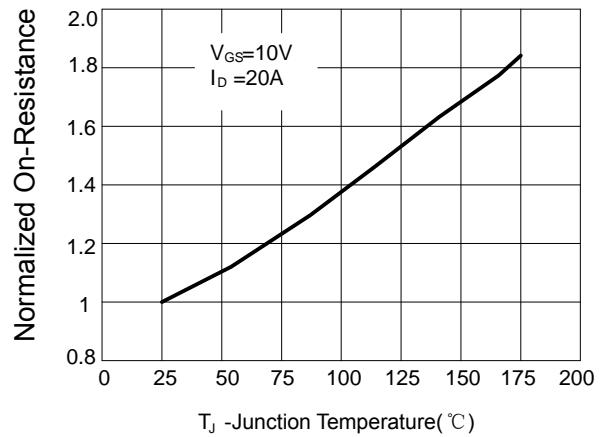


Figure 4: $R_{DS(on)}$ -junction temperature

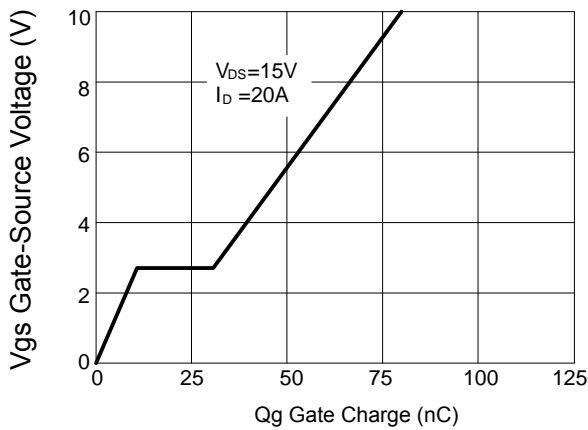


Figure 5: Gate charge

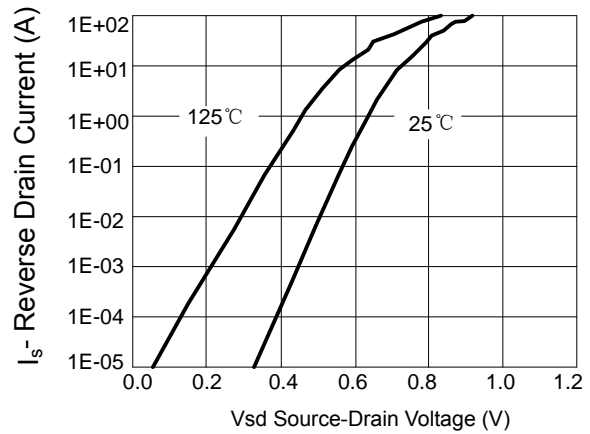


Figure 6: Source-drain diode forward

■ TYPICAL CHARACTERISTICS(Cont,)

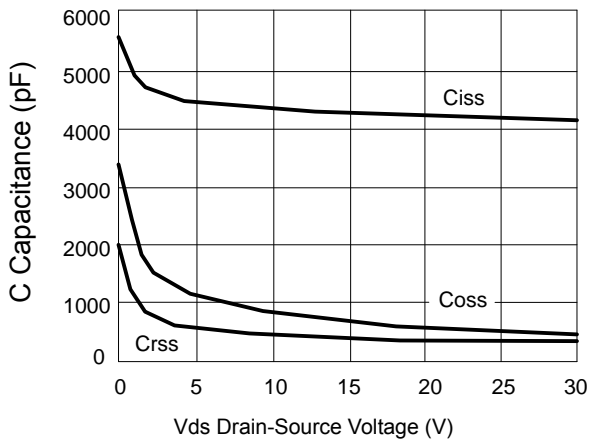


Figure 7:Capacitance vs vds

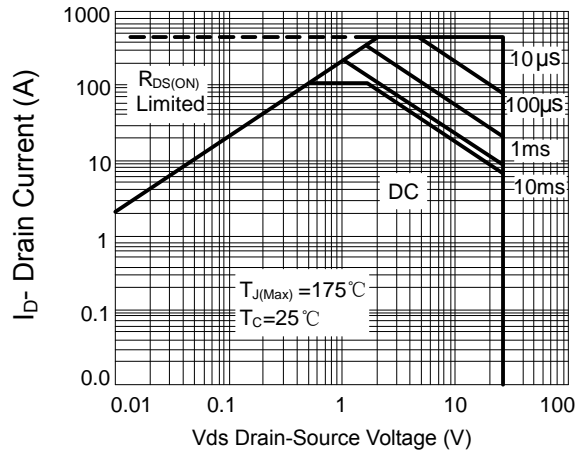


Figure 8:Safe operating area

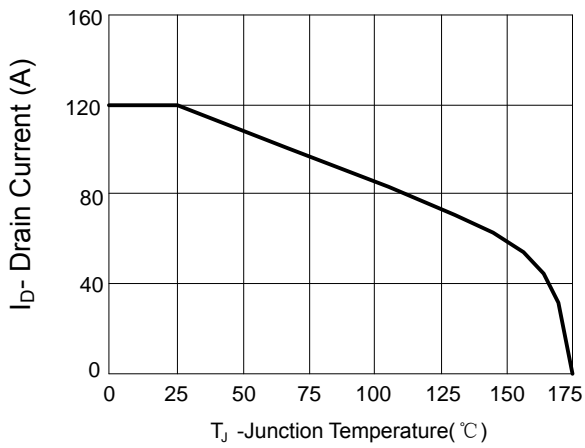


Figure 9:Current de-rating

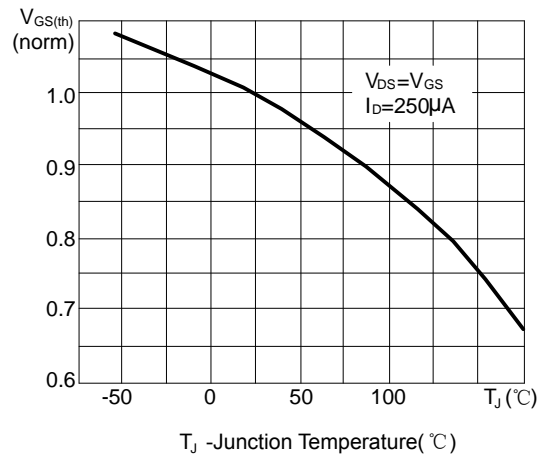
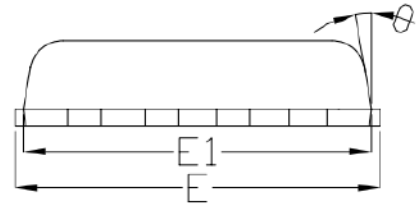
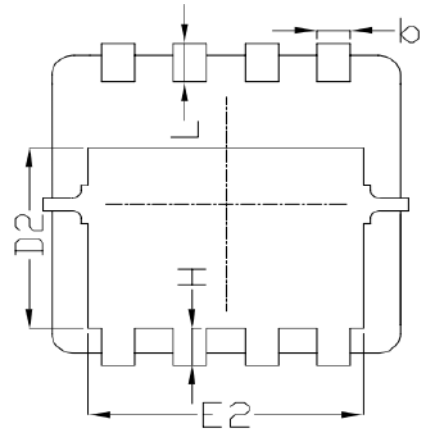
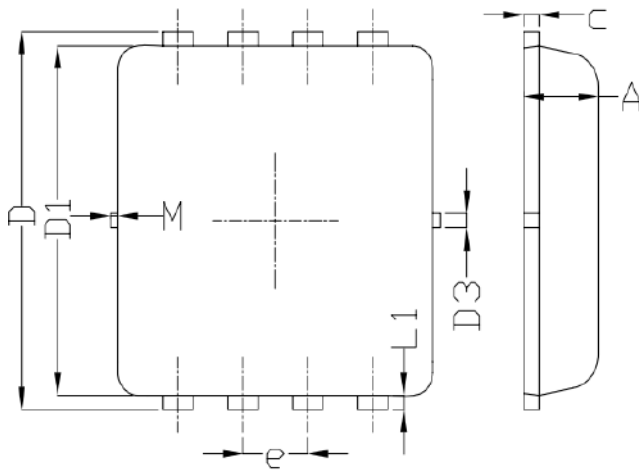
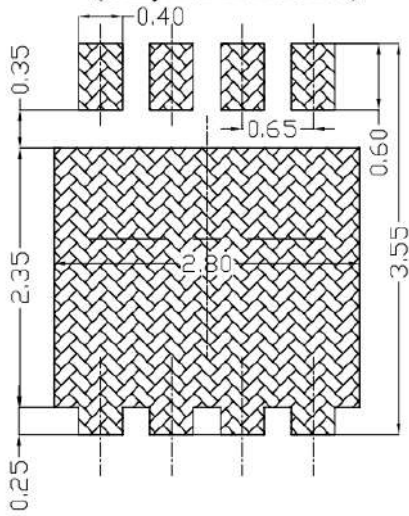


Figure 10:Vgs vs junction temperature

■ PDFN3X3-8L Package Mechanical Data



Land Pattern
(Only for Reference)



SYMBOL	DIMENSIONAL REOMTS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
b	0.25	0.30	0.35
c	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.78	1.88	1.98
D3	---	0.13	---
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65BSC		
H	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	---	0.13	---
θ	---	10°	12°
M	*	*	0.15
* Not specified			

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